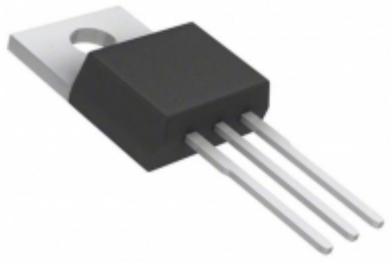


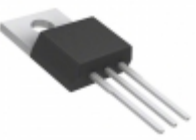





	<h2 style="color: red;">FQP16N25C</h2> <p><b>Hersteller-Teilenummer:</b> FQP16N25C</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 250V 15.6A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP16N25C.pdf</a> <a href="#">2.FQP16N25C.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 26913 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQP16N25C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 250V 15.6A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	26913 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	139W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	15.6A (Tc)
Rds On (Max) @ Id, Vgs	270 mOhm @ 7.8A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	53.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1080pF @ 25V
Verpackung	Tube

FQP16N25C ist neu im Original, Suche FQP16N25C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP16N25C Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP16N25C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FQP16N25C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 15.6A TO-220</p>	 <p><b>FQP16N25</b> Fairchild/ON Semiconductor MOSFET N-CH 250V 16A TO-220</p>	 <p><b>FQP17N08L</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p><b>FQP16N35</b> FA FQP16N35 FA</p>
 <p><b>FQP17N08</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p><b>FQP16N15</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 16.4A TO-220</p>	 <p><b>FQP17N08</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p><b>FQP16N15</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 16.4A TO-220</p>

### heiße Teile

Mehr

⊗ FQP13N50	↔ FQP13N50C	⇒ FQP13N50C	D FQP13N60C	↔ FQP140N03
⊣ FQP140N03L	⊗ FQP14N15	D FQP14N15	⇒ FQP14N30	↔ FQP14N30
⊗ FQP14N80	⊣ FQP14N80C	⊗ FQP15N16	↔ FQP15N30	↔ FQP15N50
D FQP15N60	⊗ FQP15N65	⊣ FQP15N80	⊗ FQP15P12	↔ FQP15P12
⇒ FQP16N15	↔ FQP16N15	⊗ FQP16N25	⊣ FQP16N25	↔ FQP16N25C
↔ FQP17N08	⇒ FQP17N08	D FQP17N08L	⊗ FQP17N08L	⊣ FQP17N40
⊗ FQP17N40	D FQP17P06	⇒ FQP17P06	↔ FQP17P10	↔ FQP17P10
⊣ FQP18N20V2	⊗ FQP18N20V2	↔ FQP18N50V2	⇒ FQP18N50V2	↔ FQP19N10
⊗ FQP19N10	⊣ FQP19N10L	⊗ FQP19N10L	D FQP19N20	↔ FQP19N20
↔ FQP19N20C	⊗ FQP19N20C	⊣ FQP19N20L	⊗ FQP19N20L	↔ FQP1N60C

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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